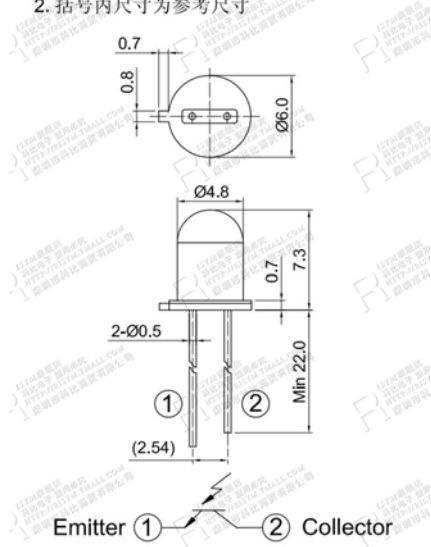


3DU5C Metal Encapsulated Silicon Phototransistor

Dimension

1. 未注尺寸公差±0.2mm
2. 括号内尺寸为参考尺寸



Specification

- NPN Silicon Phototransistor; Model : 3DU5C
- Working Voltage(Max.) : 10V;
- Reverse Breakdown Voltage : 15V;
- Dark Current : 0.3uA
- Photocurrent : 0.5-1mA;
- Power Consumption : 30mW;
- Peak Wavelength : 880nm
- Body Size : 7 x 5mm/ 0.28" x 0.2"(L*D);
- Total Length : 28mm/ 1.1";
- External Material : Metal
- Weight : 3g;